

Technical Data Data Sheet N2114, Rev. A





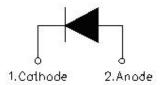
## SDUR30Q60W ULTRAFAST RECTIFIER



# Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**



#### **Features:**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- · High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	30	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	300	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 30A, Pulse, T <sub>J</sub> = 25°C	1.56	1.80	V
	$V_{F2}$	@ 30A, Pulse, T <sub>J</sub> = 125°C	1.40	1.60	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> ,T <sub>J</sub> =25°C	0.02	10	uA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> =125°C	0.006	1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA,I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	28	40	ns

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%



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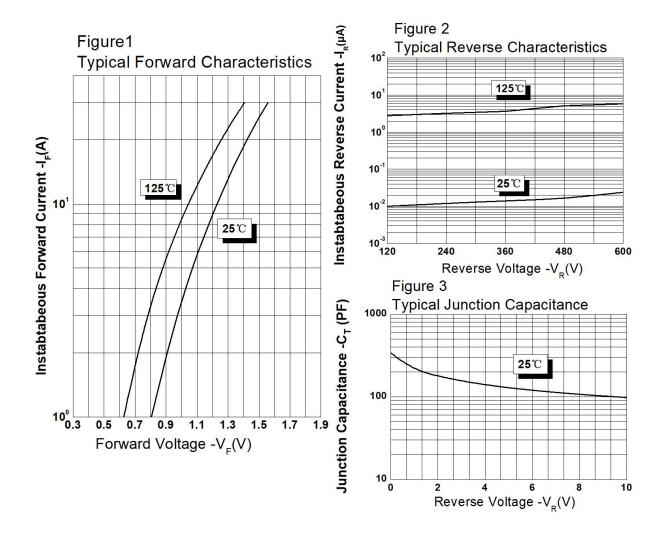




#### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	1.15	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

## **Ratings and Characteristics Curves**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

http://www.smc-diodes.com - sales@ smc-diodes.com •

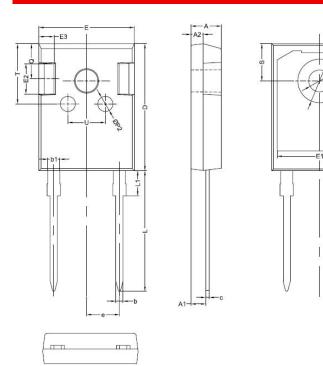


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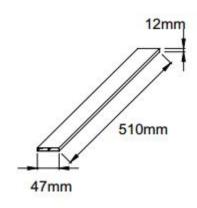


## **Mechanical Dimensions TO-247AC**



SYMBOL	Millimeters			
STWBUL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
р	1.10	1.20	1.35	
b1	1.80	2.00	2.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.58		
D2		1.17		
E	15.60	15.80	16.00	
E1		14.02		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.42	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1	7.19	7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
Т		10.00		
U		6.20		

#### **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 30 = Forward Current (30A)

Q = Q

60 = Reverse Voltage (600V) W = Configuration

Cautions: Molding resin

Epoxy resin UL:94V-0

#### **Ordering Information:**

Device	Package	Shipping	
SDUR30Q60W	TO-247AC(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

#### SDUR30Q60W



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